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Dade

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Jeffrey B. Johnson, et al.

Docket: BUR920010011US1(14331)

Serial No.: Unassigned

Dated: May 16, 2001

Filed: Herewith

For: PROCESS FOR MAKING A HIGH
VOLTAGE NPN BIPOLAR DEVICE
WITH IMPROVED AC PERFORMANCE

JC929 U.S. PRO
09/866319
05/25/01

Assistant Commissioner for Patents
Washington, DC 20231

INFORMATION DISCLOSURE STATEMENT

Sir:

In accordance with 37 C.F.R. §§ 1.97 and 1.98, it is requested that the following references, which are also listed on the attached Form PTO-1449, be made of record in the above-identified case.

1. Palestri, P., et al., "A Better Insight into the Performance of Silicon BJT's Featuring Highly Nonuniform Collector Doping Profiles," IEEE Transactions On Electron Devices, Col. 47, No. 5, May 2000, pp. 1044-1051;

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Dated: _____

2. van Noort, W.D., et al., "Reduction of UHF Power Transistor Distortion with a Non-Uniform Collector Doping Profile," IEEE BCTM 7.2, (2000), pp. 126-129; and

Applicant is submitting copies of the above-cited references.

Inasmuch as this Information Disclosure Statement is being submitted in accordance with the schedule set out in 37 C.F.R. § 1.97(b), no petition, certification or fee is required.

Respectfully submitted,



Leslie S. Szivos
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LSS:gc